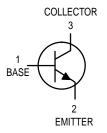
VHF Transistor

NPN Silicon



MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|---|-----------------------------------|-------------|-------------|
| Collector-Emitter Voltage | VCEO | 30 | Vdc |
| Collector-Base Voltage | V _{CBO} | 40 | Vdc |
| Emitter-Base Voltage | V _{EBO} | 4.0 | Vdc |
| Collector Current – Continuous | IC | 50 | mAdc |
| Total Device Dissipation @ T _A = 25°C Derate above 25°C | PD | 350 2.8 | mW mW/°C |
| Operating and Storage Junction Temperature Range | T _J , T _{Stg} | -55 to +135 | °C |

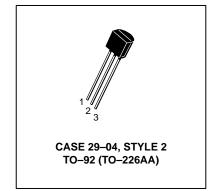
THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|---|-----------------|-----|------|
| Thermal Resistance, Junction to Ambient | $R_{\theta JA}$ | 357 | °C/W |

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

| Characteristic | Symbol | Min | Тур | Max | Unit | |
|---|-----------------|-----|------|------|------|--|
| OFF CHARACTERISTICS | | | | | | |
| Collector-Emitter Breakdown Voltage (I _C = 1.0 mAdc, I _B = 0) | V(BR)CEO | 30 | _ | _ | Vdc | |
| Collector-Base Breakdown Voltage (IC = 100 µAdc, IE = 0) | V(BR)CBO | 40 | _ | _ | Vdc | |
| Emitter-Base Breakdown Voltage ($I_E = 10 \mu Adc, I_C = 0$) | V(BR)EBO | 4.0 | _ | _ | Vdc | |
| Collector Cutoff Current (V _{CB} = 15 Vdc, I _E = 0) | ICBO | _ | _ | 50 | nAdc | |
| ON CHARACTERISTICS | | | | | | |
| DC Current Gain (IC = 8.0 mAdc, VCE = 10 Vdc) | hFE | 30 | _ | _ | _ | |
| SMALL-SIGNAL CHARACTERISTICS | | | | | | |
| Current-Gain — Bandwidth Product (I _C = 8.0 mAdc, V _{CE} = 10 Vdc, f = 100 MHz) | fT | 400 | 620 | _ | MHz | |
| Collector–Base Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 1.0 MHz) | C _{cb} | _ | 0.25 | 0.36 | pF | |
| Conversion Gain | GC | | | | dB | |
| (213 MHz to 45 MHz) ($I_C = 8.0 \text{ mAdc}$, $V_{CC} = 20 \text{ Vdc}$, Oscillator Injection = 150 mVrms) (60 MHz to 45 MHz) | | 19 | 24 | _ | | |
| (I _C = 8.0 mAdc, V _{CC} = 20 Vdc, Oscillator Injection = 150 mVrms) | | 24 | 29 | _ | | |



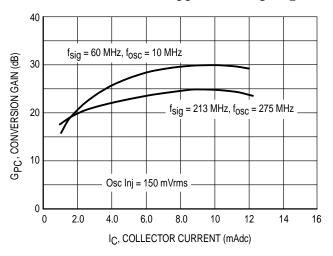




CONVERSION GAIN CHARACTERISTICS

(TEST CIRCUIT FIGURE 7)

 $(V_{CC} = 20 \text{ Vdc}, R_S = R_L = 50 \text{ Ohms}, f_{if} = 44 \text{ MHz}, B.W. = 6.0 \text{ MHz})$



40

f_{sig} = 60 MHz, f_{osc} = 104 MHz

20

f_{sig} = 213 MHz, f_{osc} = 275 MHz

I_C = 8.0 mAdc

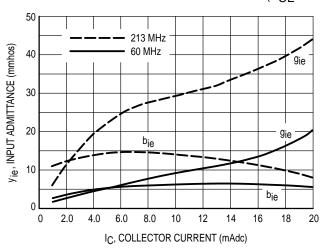
V_i, OSCILLATOR INJECTION (mV)

Figure 1. Conversion Gain versus Collector Current

Figure 2. Conversion Gain versus Injection Level

COMMON-EMITTER y PARAMETERS

 $(VCE = 15 Vdc, TA = 25^{\circ}C)$



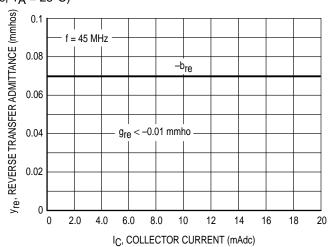


Figure 3. Input Admittance

y_{fe}, FORWARD TRANSFER ADMITTANCE (mmhos) 200 = 45 MHz 160 120 80 bfe 0 2.0 4.0 8.0 10 12 16 18 20 IC, COLLECTOR CURRENT (mAdc)

Figure 4. Reverse Transfer Admittance

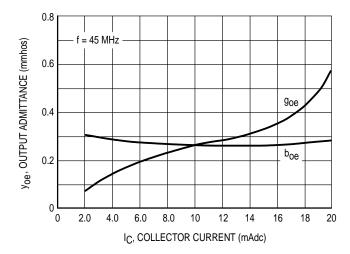


Figure 5. Forward Transfer Admittance

Figure 6. Output Admittance

| fsig | 60 MHz | 213 MHz |
|------|--------------------------------|--|
| fosc | 105 MHz | 258 MHz |
| C1 | 1.5–20 pF | 1.5–20 pF |
| C2 | 8.0–60 pF | 6.0–12 pF |
| C3 | 8.0–60 pF | 1.5–20 pF |
| C4 | 3.0–35 pF | _ |
| C5 | 1.5–20 pF | _ |
| L1 | 5 Turns #26 Air, Tap 1 Turn | 3 Turns #16 Air, Tap ¹ / ₂ Turn |
| L2 | 10 Turns #26 Air | 10 Turns #26 Arnold A1–10 Core |
| L3 | Ohmite Z235 | _ |

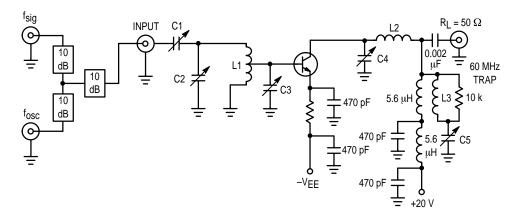
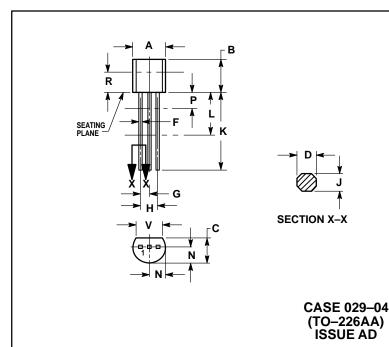


Figure 7. VHF Mixer Test Circuit (f_{if} = 44 MHz, B.W. = 6.0 MHz)

PACKAGE DIMENSIONS



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- DIMENSION F APPLIES BETWEEN P AND L DIMENSION P APPLIES BETWEEN F AND L.
 DIMENSION D AND J APPLY BETWEEN L AND K
 MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

| | INCHES | | MILLIM | IETERS |
|-----|--------|-------|--------|--------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.175 | 0.205 | 4.45 | 5.20 |
| В | 0.170 | 0.210 | 4.32 | 5.33 |
| С | 0.125 | 0.165 | 3.18 | 4.19 |
| D | 0.016 | 0.022 | 0.41 | 0.55 |
| F | 0.016 | 0.019 | 0.41 | 0.48 |
| G | 0.045 | 0.055 | 1.15 | 1.39 |
| Н | 0.095 | 0.105 | 2.42 | 2.66 |
| J | 0.015 | 0.020 | 0.39 | 0.50 |
| K | 0.500 | | 12.70 | |
| L | 0.250 | | 6.35 | |
| N | 0.080 | 0.105 | 2.04 | 2.66 |
| Р | | 0.100 | | 2.54 |
| R | 0.115 | | 2.93 | |
| V | 0.135 | | 3 43 | |

PIN 1. BASE

2. EMITTER 3. COLLECTOR

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